

Rev.5.0 Aug.28 2024

JSKT070/JSKH070

Description

- 1) A package of series of two chips.
- 2) With high thermal conductivity DBC as the insulation.
- 3) Welding by vacuum welding technology, which provide high reliability.

Typical Application

DC motor control, temperature control and light control system.



Absolute Maximum Ratings (Packaged into modules, unless otherwise specified, T_{CASE}=25°C)

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Parameter	Test Conditions	Symbol	Values			
			12	16	18	Unit
Operating junction temperature range		TJ	-40-125			°C
Storage temperature range		T _{STG}	-40-125			°C
Repetitive peak off-state voltage	T J =25 ℃	V _{DRM}	1200	1600	1800	V
Repetitive peak reverse voltage	TJ =25 ℃	V _{RRM}	1200	1600	1800	V
Non-repetitive peak off-state voltage	T J =25 ℃	VDSM	1300	1700	1900	V
Non-repetitive peak reverse voltage	T J =25 ℃	V _{RSM}	1300	1700	1900	V
Average on-state current	Tc =85 ℃	It(av)/If(av)	70		А	
Peak on-state surge current	t _P =10ms V _R =0.6V _{RRM}	Itsm/Ifsm	1400		А	
l ² t value for fusing	tp=10ms Vr=0.6Vrrm	l ² t	9800		A ² s	
Critical rate of rise of on-state current	IG=2×IGT	di/dt	150		A/µs	
Insulation voltage	A.C 50Hz(1s/1min)	Viso	3600/3000		V	

Electrical Characteristics (Packaged into modules, unless otherwise specified, T_{CASE} =25°C)

Parameter	Test Conditions	Symbol	Values	Unit
Peak on-state voltage	I⊤=210A t⊳=380µs	V _{TM}	≤1.8	V
Threshold voltage	T J=125 ℃	V _{TO}	≤0.95	V
Dynamic resistance	TJ=125℃	R₀	≤3.7	mΩ
	V _D =V _{DRM}			
Repetitive peak off-state current	Tc=25°C	IDRM1	≤100	μA
	Tc=125℃	Idrm2	≤30	mA



Repetitive peak reverse current	VR=V _{RRM} T _C =25℃ T _C =125℃	Irrm1 Irrm2	≤100 ≤30	μA mA
Triggering gate current	$V_D=12V R_L=30\Omega$	Ідт	20-120	mA
Holding current	I⊤=1A	Iн	≤250	mA
Latching current	I _G =1.2 I _{GT}	١L	≤300	mA
Triggering gate voltage	$V_D=12V R_L=30\Omega$	V _{GT}	≤1.8	V
Non triggering gate voltage	V _D =V _{DRM} T _J =125℃	Vgd	≥0.25	V
Critical rate of rise of voltage	V _D =2/3V _{DRM} TJ=125℃ Gate Open	dv/dt	≥1000	V/µs
Thermal resistance	Junction to case Case to heatsink	Rth(j-c) Rth(c-s)	0.37 0.22	°C/W



Mechanical Characteristics

Aechanical Characteristics			
Module size	93mm×21mm		
Module height	30mm		
Terminal distance of (1) /(2) /(3)	20mm		
Mounting torque(M5)	5±15%Nm		
Terminal torque(M5)	3±15%Nm		
et e			
(1) • • (2) • (3) • (3) • (1) • • (2) • • (3) • (3) • (1) • • (1)			
JSKT symbol			
(1) • • (2) • (3) • • (3) • • • • • • • • • • • • • • • • • • •			
JSKH symbol			



Instructions and Precautions

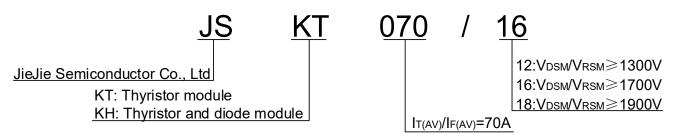
1) There is no severe vibration and shock in operating environment, and there should be no impurity and atmosphere which may corrode metal and damage the insulation in the air-dielectric.

2) The operating condition of the product can't out of range of the above parameters.

3) When the product is installed on the radiator, the radiator's surface should be confirmed flat, smooth, wipe clean with alcohol, and coated evenly with a layer of thermal grease which thickness is moderate on the contact surface between product and radiator. When the module is fastened on the surface of the radiator, the M5 or M6 screws and spring washers are used and fastened with 5NM torque. After the module is operated 1 hour, all screws must be refastened.

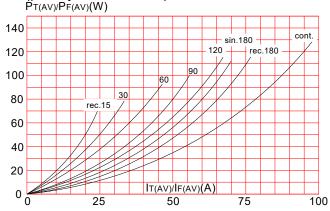
4) The connection with the main electrode of module can use copper, welding, socket and so on. The contact surface should be smooth and flat, which make good contact. While the connection with the control electrode of module is installed, attention should be paid to the corresponding connection of each pin. After the completion of the connection, do not plug and pull out the lead of the control electrode freely.

Ordering Information



Performance Curves

FIG.1:Power dissipation vs. on-state current (per thyristor or diode)



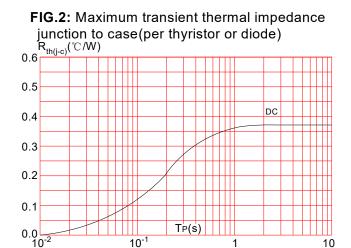
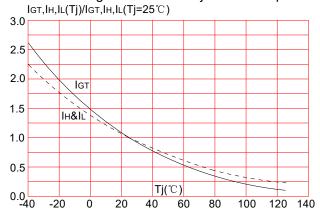




FIG.4: Relative variations of gate trigger current, holding current and latching current versus junction temperature $\log \ln \ln (Ti)/\log \ln \ln (Ti=25^\circ)$



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